COMPLIANT

HALOGEN

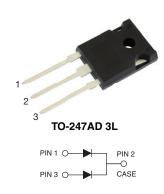
FREE



Vishay General Semiconductor

Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.44 \text{ V}$ at $I_F = 10 \text{ A}$



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 40 A				
V_{RRM}	100 V				
I _{FSM}	550 A				
V_F at $I_F = 40$ A $(T_J = 125 ^{\circ}\text{C})$	0.66 V				
T _J max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Common cathode				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Polarity: as marked

Mounting torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VX80M100PW	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	100	V		
Maximum average forward rectified current (fig. 1)	per device		80	А		
	per diode	I _{F(AV)}	40			
Peak forward surge current 8.3 ms single half superimposed on rated load	sine-wave	I _{FSM}	550	А		
Operating junction temperature range		T _J ⁽¹⁾	-40 to +175	%0		
Storage temperature range		T _{STG}	-40 to +175	°C		

Note

 $^{^{(1)}}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



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ELECTRICAL CHARACTERISTICS (T _J = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
	I _F = 10 A		V _F ⁽¹⁾	0.52	-	V
	I _F = 20 A	$T_J = 25 ^{\circ}C$		0.61	-	
Instantance in forward voltage per diede	I _F = 40 A			0.77	0.84	
Instantaneous forward voltage per diode	I _F = 10 A	T _J = 125 °C		0.44	-	
	I _F = 20 A			0.55	-	
	I _F = 40 A			0.66	0.74	
Reverse current at rated V _R per diode	V _R = 70 V	T _J = 25 °C	I _R ⁽²⁾	0.0055	-	mA
	v _R = 70 v	T _J = 125 °C		5	-	
	\/ - 100 \/	T _J = 25 °C		-	0.6	
	V _R = 100 V	T _J = 125 °C		9	35	
Typical junction capacitance	4.0 V,	4.0 V, 1 MHz		3400	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 5 \text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	PARAMETER SYMBOL VX80M100PW UNIT				
Typical thermal resistance per device	R ₀ JC (1)	0.6	°C/W		

Note

(1) Thermal resistance junction-to-case to follow JEDEC® 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
VX80M100PW-M3/P	5.64	Р	25/tube	Tube		
VX80M100PWHM3/P (1)	5.64	Р	25/tube	Tube		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C, unless otherwise noted)

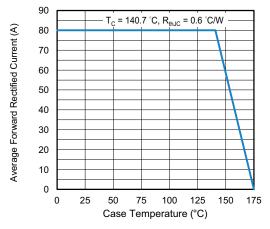


Fig. 1 - Maximum Forward Current Derating Curve

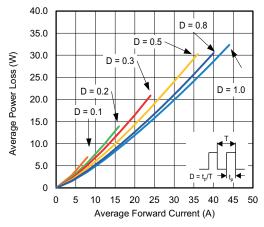


Fig. 2 - Average Power Loss Characteristics

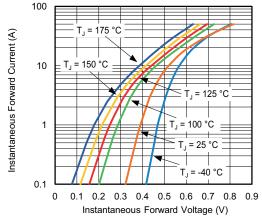


Fig. 3 - Typical Instantaneous Forward Characteristics

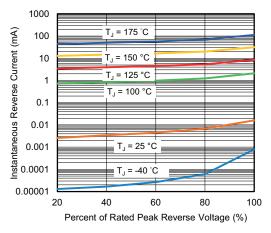


Fig. 4 - Typical Reverse Leakage Characteristics

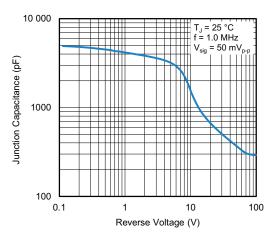


Fig. 5 - Typical Junction Capacitance

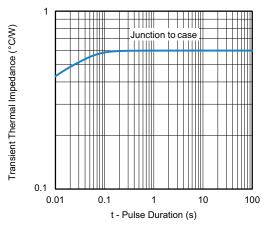
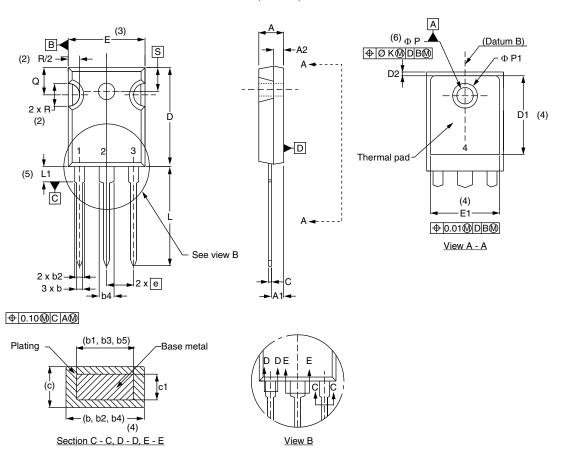


Fig. 6 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in millimeters (inches) TO-247AD 3L



SYMBOL	MILLIN	MILLIMETERS		INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
b4	2.59	3.43	0.102	0.135		
b5	2.59	3.38	0.102	0.133		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	0.254)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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